

# isc Silicon NPN Power Transistor

### **DESCRIPTION**

- · Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= 140V(Min)
- Complement to Type 2SB705
- · High Power Dissipation
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

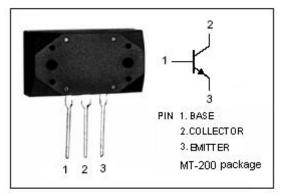
### **APPLICATIONS**

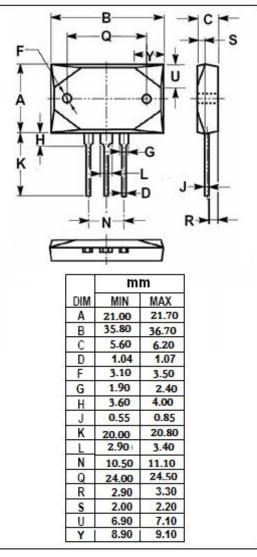


- · For audio frequency power amplifier applications
- Suitable for output stages of 60~120 watts audio amplifier and voltage regulations.

## ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	140	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	140	V	
V <sub>EBO</sub>	Emitter-Base Voltage	5	V	
Ic	Collector Current-Continuous	10	А	
Ісм	Collector Current-Peak	15	А	
Pc	Pc Collector Power Dissipation @ T <sub>C</sub> =25°C		W	
TJ	Junction Temperature 150		$^{\circ}$	
T <sub>stg</sub>	Storage Temperature Range -55~150		$^{\circ}$	







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2SD745

## **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 5A; I <sub>B</sub> = 0.5A			1.5	V	
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 5A; I <sub>B</sub> = 0.5A			2.0	V	
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 140V; I <sub>E</sub> = 0			50	μА	
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 3V; I <sub>C</sub> = 0			50	μА	
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 50mA; V <sub>CE</sub> = 5V	20	55			
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 2A; V <sub>CE</sub> = 5V	40	80	200		
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V; f <sub>test</sub> = 1.0MHz		270		pF	
fτ	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.2A; V <sub>CE</sub> = 5V		15		MHz	

## ♦ h<sub>FE-2</sub> Classifications

S	R	Q
40-80	60-120	100-200

## **NOTICE:**

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